

X00128

SFT5659

15 AMP

HIGH SPEED NPN TRANSISTOR

150 VOLTS



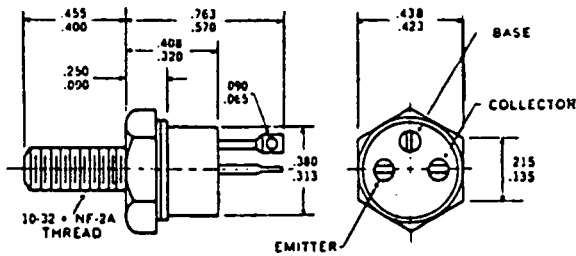
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CASE STYLE TO-59

FEATURES

All Terminals Isolated From Case

- ▶ RADIATION TOLERANT
- ▶ FAST SWITCHING, 150ns MAX t_{on}
- ▶ HIGH FREQUENCY, TYPICAL f_T 100MHz
- ▶ V_{CE0} 80 VOLTS MINIMUM
- ▶ HIGH GAIN, VERY LOW SATURATION VOLTAGE
- ▶ GOLD EUTECTIC DIE ATTACH
- ▶ DESIGNED FOR COMPLEMENTARY USE WITH SFT6189



MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Collector-Emitter Voltage	V_{CE0}	80	Volts
Collector-Base Voltage	V_{CB0}	150	Volts
Emitter-Base Voltage	V_{EB0}	8	Volts
Collector Current	I_C	15	Amps
Base Current	I_B	2	Amps
Total Device Dissipation @ $T_c = 100^\circ C$ Derate Above 100°C	P_D	30 500	Watts mW/°C
Operating and Storage Temperature	T_J, T_{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	VALUE	UNIT
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.0	°C/W

ELECTRICAL CHARACTERISTICS

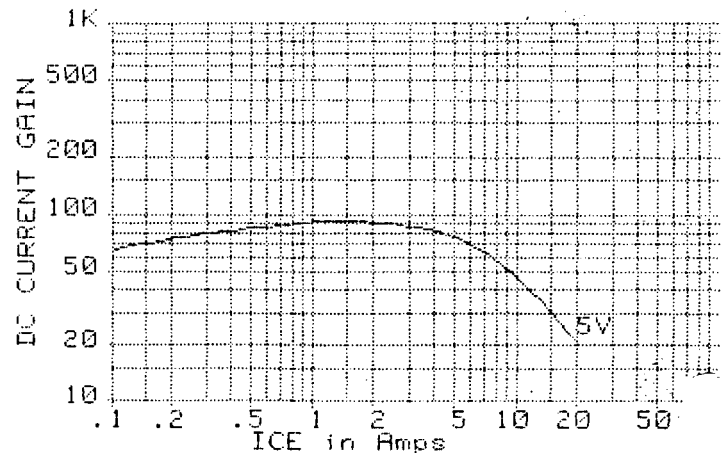
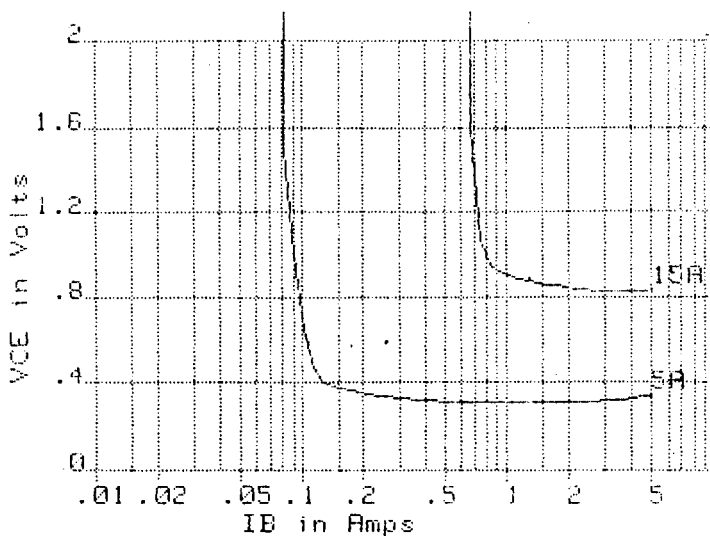
Characteristics	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage* ($I_C = 100mA_{dc}$)	V_{CE0}	80		Volts
Collector-Base Breakdown Voltage ($I_C = 200\mu A_{dc}$)	V_{CB0}	150		Volts

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
Emitter-Base Breakdown Voltage ($I_E = 200\mu\text{A}$)	BVEBO	8		Vdc
Collector Cutoff Current ($V_{CE} = 60\text{Vdc}$)	ICEO		10	μA
Collector Cutoff Current ($V_{CB} = 100\text{Vdc}$)	ICBO		1	μA
Emitter Cutoff Current ($V_{EB} = 6\text{Vdc}$)	IEBO		1	μA
DC Current Gain* ($I_C = 5\text{A}$, $V_{CE} = 5\text{Vdc}$) ($I_C = 10\text{A}$, $V_{CE} = 5\text{Vdc}$) ($I_C = 15\text{A}$, $V_{CE} = 5\text{Vdc}$)	hFE	50 30 20	250 150	
Collector-Emitter Saturation Voltage* ($I_C = 5\text{A}$, $I_B = 500\text{mA}$) ($I_C = 15\text{A}$, $I_B = 1.5\text{A}$)	VCE(SAT)		0.5 1.5	Vdc
Base-Emitter Saturation Voltage* ($I_C = 5\text{A}$, $I_B = 500\text{mA}$) ($I_C = 15\text{A}$, $I_B = 1.5\text{A}$)	VBE(SAT)		1.2 1.5	Vdc
Current Gain Bandwidth Product ($I_C = 500\text{mA}$, $V_{CE} = 5\text{Vdc}$, $f = 10\text{MHz}$)	fT	70		MHz
Output Capacitance ($V_{CB} = 10\text{Vdc}$, $I_E = 0\text{A}$, $f = 1\text{MHz}$)	Cob		150	pf
Turn On Time ($V_{CC} = 25\text{Vdc}$, $I_C = 5\text{A}$, $I_{B1} = I_{B2} = 250\text{mA}$, Base - Emitter clamp diode = 1N5802 or equivalent)	t(on)		150	ns
Turn Off Time	t(off)		800	ns

*Pulse Test: Pulse Width = 300 μs , Duty Cycle = 2%

TYPICAL OPERATING CURVES



SOLID STATE DEVICES, INC.